PCN Numb	oer:	202207	22001.2		PCN	Date:	September 26, 2022	
Title:	Qualification o	of new Pr	ocess Technology	and Die Cha	inge 1	for select	DRV5013 devices	
Customer	Contact:	PC	N Manager		Dept		Quality Services	
Proposed	1 st Ship Date:	Ma	arch 26, 2023	Sample accepte			October 26, 2022*	
_	•	ved afte	r October 26, 202	22 will not b	e sup	ported.		
Change Ty	· -		1					
	mbly Site		Assembly Proc Electrical Spec		\mathbb{H}		oly Materials	
☑ Desig☐ Test			Packing/Shippi		H	Test Pr	nical Specification	
	r Bump Site		Wafer Bump M		H		Bump Process	
	r Fab Site		Wafer Fab Mat				ab Process	
·			Part number c					
			Notification	Details				
	n of Change:							
RFAB and o	die change as li		mounce the qualiful with the product			process te	echnology (LBC9) in	
Fa	ab Site		ent Process	New F				
	RFAB	16	echnology LBC8	Techi		y		
	NI AD		LDCo	LL	LBC9			
In support of the qualification of the new process technology, the devices will undergo a die change. Qual details are provided in the Qual Data Section.								
Reason fo	r Change:							
Continuity	of supply							
Anticipate	d impact on F	it, Form	Function, Qual	ty or Reliab	ility (positive	/ negative):	
None.								
Changes t	o product ider	ntificatio	n resulting from	this PCN:				
The Die Revision will change as shown in the table and sample label below: Current New								
Die Rev [2P] Die Rev [2P] A0, A1 B								
Sample product shipping label (not actual product label)								
TEXAS INSTRUMENTS MADE IN: Malaysia 20C: 20: (A) TO: 1750 MSL '2 /260C/1 YEAR SEAL DT 03/29/04 OPT: 1TEM: 39 [BI: 5A () TO: 1750 [CP) REV: (V) 0033317 [CP) REV: (V) 0033317 [CP) REV: (V) 0033317 [CP) REV: (V) 0033317 [COL: 550: MHz (21L.) CCO: USA								

Product Affected:			
DRV5013ADEDBZRQ1	DRV5013ADEDBZTQ1	DRV5013ADQDBZRQ1	DRV5013ADQDBZTQ1
DRV5013FAEDBZRQ1			

Automotive New Product Qualification Summary
(As per AEC-Q100 and JEDEC Guidelines)
DRV5013 Refresh Grade 1 Automotive DBZ in TFME
Approve Date 22-SEPTEMBER-2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

PCN# 20220722001.2

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: DRV5013ADQDBZRQ1	QBS Reference: DRV5015A2EDBZRQ1	QBS Reference: DRV5015A3EDBZRQ1
Test Group	A - Acce	elerated Enviror	nment St	ress Te	sts					
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step	1/0/0	1/0/0	2/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	1/77/0	2/156/0
AC/UHAST	А3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	-	1/77/0	2/154/0
AC/UHAST	А3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	-	
TC	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	1/77/0	1/77/0	2/154/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	1/5/0	1/5/0	1/5/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	1/45/0	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	1000 Hours	-	-	1/77/0
Test Group	B - Acce	elerated Lifetime	e Simula	tion Tes	ts					
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	125C	1000 Hours	1/77/0	-	-
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	150C	1000 Hours	-	-	3/231/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	48 Hours	-	-	2/1600/0
Test Group	Test Group C - Package Assembly Integrity Tests									
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device	QBS Reference	QBS Reference
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90	1/30/0	1/30/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	1/6/0	1/6/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-	-
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	2000 Volts	-	1/3/0	1/3/0
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	5000 Volts	-	1/3/0	1/3/0
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0	-	-
Test Group	E - Elect	trical Verificatio	n Tests							
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group D - Die Fabrication Reliability Tests										
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	-	-
SD	СЗ	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0
SD	С3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47:-55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL, ED
- Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAS⁻

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) DRV5013 Refresh Grade 0 Automotive DBZ in TFME Approve Date 22-SEPTEMBER-2022

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

			Jata	Dispi	ayeu as. Ivi	allibei oi	1013 / 1	otal sample size	e / Total laneu		
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: DRV5013ADEDBZRQ1	Qual Device: DRV5013FAEDBZRQ1	QBS Reference: DRV5015A2EDBZRQ1	QBS Reference: DRV5015A3EDBZRQ1
Test Group	A - Acce	elerated Enviror	nment St	ress Te	sts						
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL1 260C	1 Step	1/0/0	-	1/0/0	2/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	1/77/0	-	1/77/0	2/156/0
AC/UHAST	А3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	-	-	1/77/0	2/154/0
AC/UHAST	А3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	-	-	-
TC	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycling	-65C to 150C	1654 Cycles	1/77/0	-	1/77/0	2/154/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post TC ball Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Units	1/5/0	-	1/5/0	1/5/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	2000 Hours	1/45/0	-	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	1000 Hours	-	-	-	1/77/0
Test Group	B - Acce	elerated Lifetime	e Simula	tion Tes	ts						
HTOL	B1	JEDEC JESD22- A108	1	77	Life Test	150C	1000 Hours	1/77/0	-	-	3/231/0
ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	150C	48 Hours	-	-	-	2/1600/0
Test Group	C - Pack	age Assembly	Integrity	Tests							
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	-
SD	C3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	-	1/15/0
SD	C3	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	-	-	-

Test Group	D - Die F	abrication Relia	ability Te	sts							
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	trical Verificatio	n Tests								
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0	-	-	-
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	5000 Volts	-	-	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	2000 Volts	-	-	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-	-	-
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	-	1/6/0	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	2/60/0	1/30/0	1/30/0	1/30/0
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device	Qual Device	QBS Reference	QBS Reference

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E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL, ED
- Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

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